

RJF0411JPD

40V, 34A Silicon N Channel Thermal FET Power Switching

R07DS1258EJ0100 Rev.1.00 Jun 23, 2015

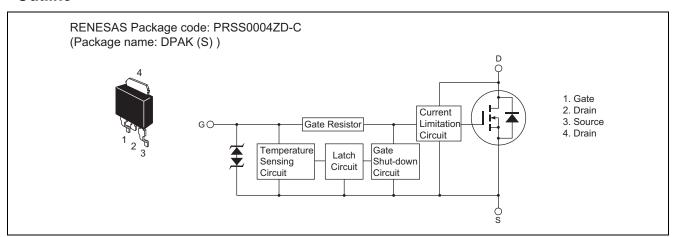
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation.
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- Power supply voltage applies 12 V.
- AEC-Q101 Compliant.
- Endurance capability against to ESD.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	40	V
Gate to source voltage	V _{GSS}	16	V
Gate to source voltage	V _{GSS}	-2.5	V
Drain current	I _D Note3	34	Α
Body-drain diode reverse drain current	I _{DR}	34	Α
Avalanche current	I _{AP} Note 2	5	Α
Avalanche energy	E _{AR} Note 2	166	mJ
Channel dissipation	Pch Note 1	40	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. Value at Tc = 25°C

- 2. Tch = 25°C, Rg \geq 50 Ω
- 3. It provides by the current limitation lower bound value.

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	_	_	V	
	V _{IL}	_	_	1.2	V	
Input current	I _{IH1}	_	_	100	μΑ	Vi = 8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}	_	_	50	μΑ	Vi = 3.5 V, V _{DS} = 0
	IιL	_	_	1	μΑ	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}	_	0.8		mA	Vi = 8 V, V _{DS} = 0
(Gate shut down)	I _{IH(sd)2}	_	0.35		mA	Vi = 3.5 V, V _{DS} = 0
Shut down temperature	Tsd	_	175		°C	Channel temperature
Gate operation voltage	Vop	3.5	_	12	V	
Drain current	I _{D limt}	34	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V Note 4
(Current limitation value)						Tc ≤ 80°C

Note: 4. Pulse test

Electrical Characteristics

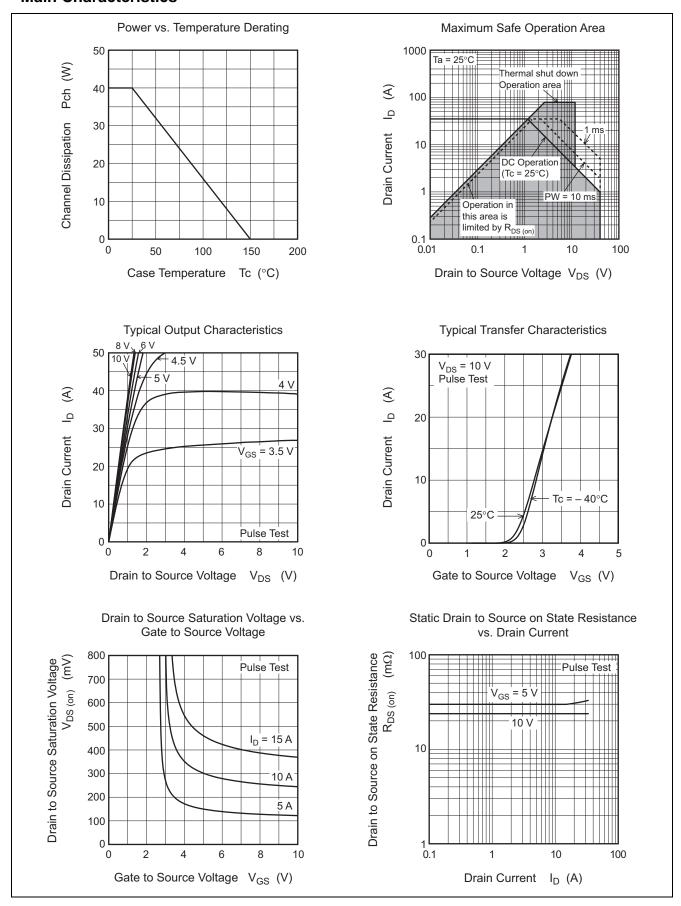
 $(Ta = 25^{\circ}C)$

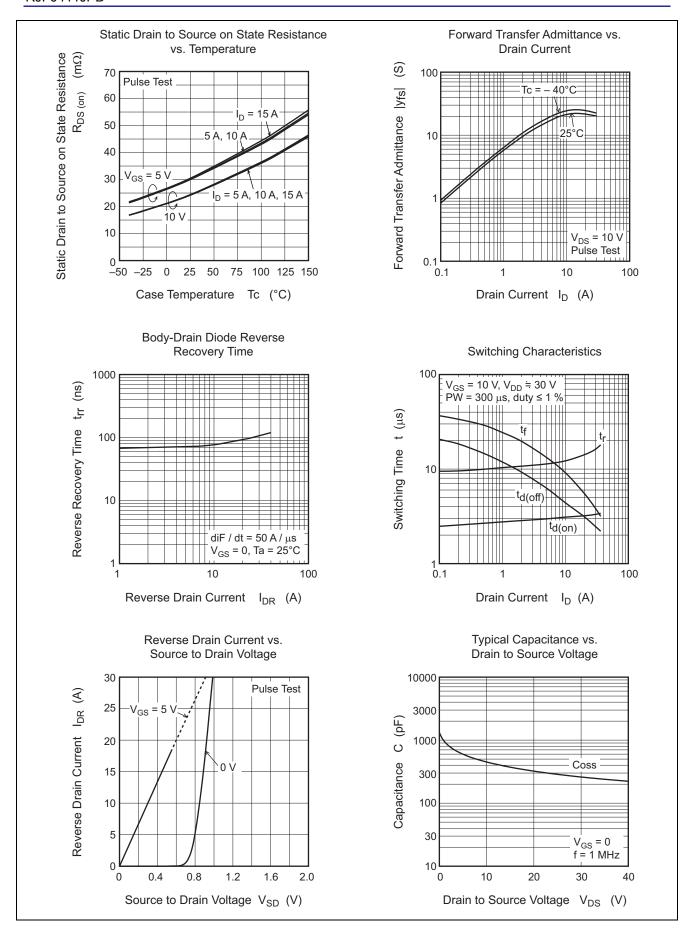
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	40	Α	V _{GS} = 3.5 V, V _{DS} = 10 V Note 5
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 10 V
	I _{D3}	34	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V Note 5
						Tc ≤ 80°C
	I_{D4}	34	_	_	Α	$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}^{\text{Note 5}}$
						Tc ≤ 80°C
Drain to source breakdown voltage	V _{(BR)DSS}	40	—	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _(BR) GSS	16	_	_	V	$I_G = 800 \mu A, V_{DS} = 0$
	V _{(BR)GSS}	-2.5	_	_	V	$I_G = -100 \mu A, V_{DS} = 0$
Gate to source leak current	I _{GSS1}	_	_	100	μΑ	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GSS2}	_	_	50	μΑ	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
	I _{GSS3}	_	_	1	μΑ	$V_{GS} = 1.2 \text{ V}, V_{DS} = 0$
	I _{GSS4}		_	-100	μΑ	$V_{GS} = -2.4 \text{ V}, V_{DS} = 0$
Input current (shut down)	IGS(OP)1		0.8	_	mA	V _{GS} = 8 V, V _{DS} = 0
	I _{GS(OP)2}		0.35	_	mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	IDSS	_	_	10	μΑ	V _{DS} = 32 V, V _{GS} = 0, Tc = 110°C
Gate to source cutoff voltage	V _{GS(off)}	1.1	_	2.1	V	V _{DS} = 10 V, I _D = 1 mA
Forward transfer admittance	y _{fs}	12	21.9		S	I _D = 15 A, V _{DS} = 10 V Note 5
Static drain to source	R _{DS(on)}	_	29.9	43	mΩ	I _D = 15 A, V _{GS} = 5 V ^{Note 5}
on state resistance	R _{DS(on)}	_	23.8	37	mΩ	I _D = 15 A, V _{GS} = 10 V Note 5
Output capacitance	Coss	_	416	_	pF	V _{DS} = 10 V, V _{GS} = 0, f = 1MHz
Turn-on delay time	t _{d(on)}	_	3	_	μS	V_{GS} = 10 V, I_{D} = 15 A, R_{L} = 2 Ω
Rise time	tr	_	12.8	_	μS	
Turn-off delay time	t _{d(off)}	_	4	_	μS	
Fall time	t _f	_	9.9	_	μS	
Body-drain diode forward voltage	V_{DF}	_	0.96	_	V	I _F = 30 A, V _{GS} = 0
Body-drain diode	t _{rr}	_	109	_	ns	I _F = 30 A, V _{GS} = 0
reverse recovery time						di _F /dt = 50 A/μs
Over load shut down	t _{os1}	_	0.26	_	ms	V _{GS} = 5 V, V _{DD} = 16 V
operation time Note 6						

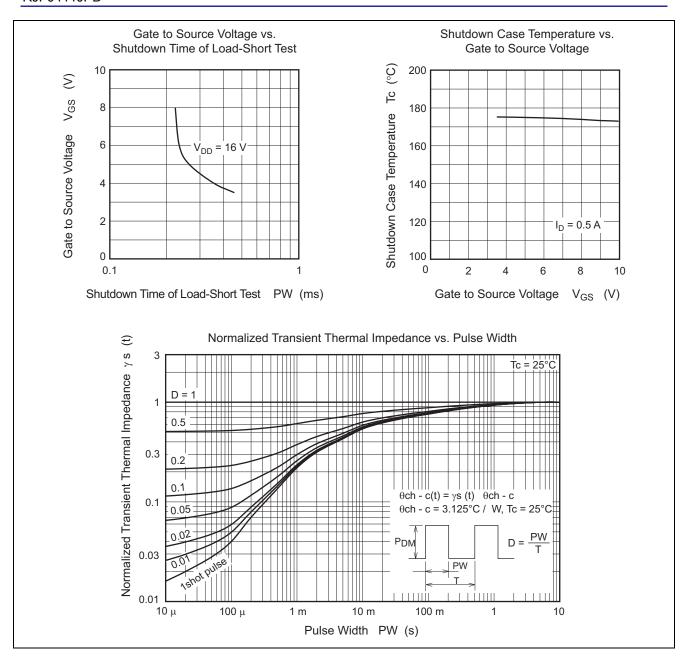
Notes: 5. Pulse test

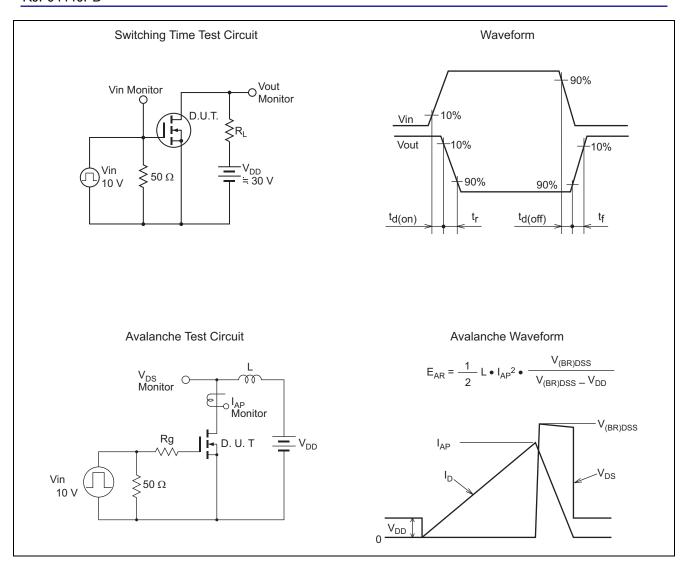
6. Including the junction temperature rise of the over loaded condition.

Main Characteristics

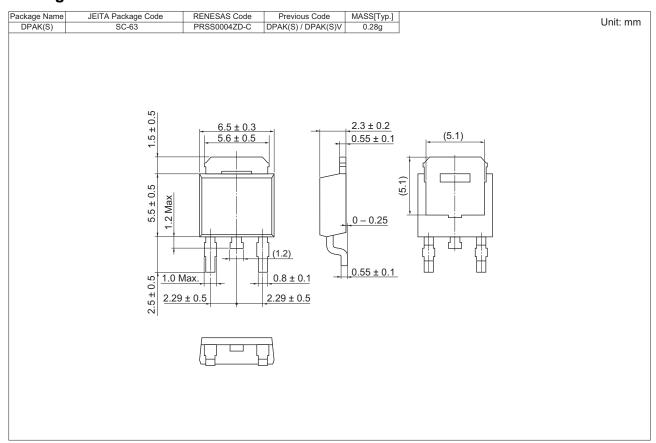








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJF0411JPD-00-J3	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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Renesas Electronics America Inc. 2801 Scott Boulevard Santa Clara, CA 95050-2549, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3 Tel: +1-905-237-2004

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-6503-0, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
Room 1709, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100191, P.R.China Tel: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, P. R. China 200333
Tel: 486-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2865-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949 TE: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tei: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd.
No.777C, 100 Feet Road, HALII Stage, Indiranagar, Bangalore, India Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd. 12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea Tel: +82-2-558-3737, Fax: +82-2-558-5141